TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VCX2244FT, TC74VCX2244FK

Low-Voltage Octal Bus Buffer with 3.6-V Tolerant Inputs and Outputs

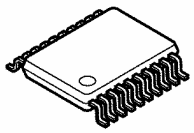
The TC74VCX2244 is a high-performance CMOS octal bus buffer. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

This device is non-inverting 3-state buffer having four active-low output enables. When the $\overline{OE}$ input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc. The 26-Ω series resistor helps reducing output overshoot and undershoot without external resistor.

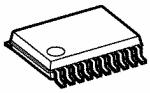
All inputs are equipped with protection circuits against static discharge.

TC74VCX2244FT



TSSOP20-P-0044-0.65A

TC74VCX2244FK



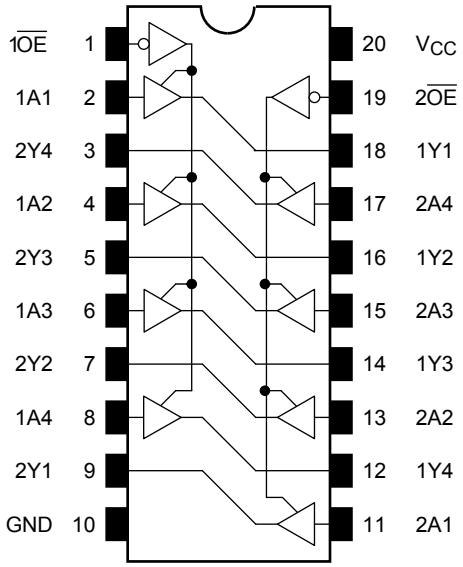
VSSOP20-P-0030-0.50

Weight
TSSOP20-P-0044-0.65A : 0.08 g (typ.)
VSSOP20-P-0030-0.50 : 0.03 g (typ.)

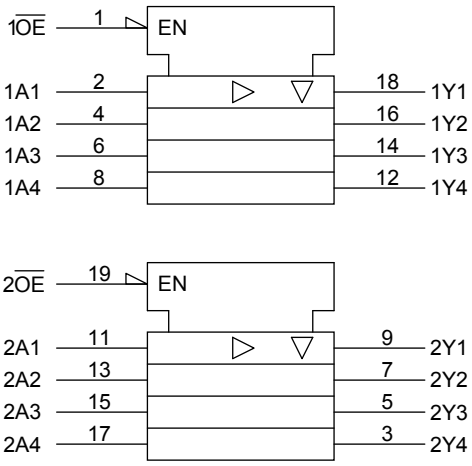
## Features

- 26-Ω series resistors on outputs.
- Low-voltage operation: $V_{CC}$ = 1.8 to 3.6 V
- High-speed operation: $t_{pd}$ = 4.4 ns (max) ($V_{CC}$ = 3.0 to 3.6 V)
  : $t_{pd}$ = 5.6 ns (max) ($V_{CC}$ = 2.3 to 2.7 V)
  : $t_{pd}$ = 9.8 ns (max) ($V_{CC}$ = 1.8 V)
- Output current: $I_{OH}/I_{OL}$ = ±12 mA (min) ($V_{CC}$ = 3.0 V)
  : $I_{OH}/I_{OL}$ = ±8 mA (min) ($V_{CC}$ = 2.3 V)
  : $I_{OH}/I_{OL}$ = ±4 mA (min) ($V_{CC}$ = 1.8 V)
- Latch-up performance: –300 mA
- ESD performance: Machine model ≥ ±200 V
  Human body model ≥ ±2000 V
- Package: TSSOP and VSSOP (US)
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

## Pin Assignment (top view)




## IEC Logic Symbol




## Truth Table

| Inputs | | Outputs |
|---|---|---|
| $\overline{OE}$ | An | |
| L | L | L |
| L | H | H |
| H | X | Z |

X: Don’t care

Z: High impedance

## Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Power supply voltage | $V_{CC}$ | −0.5 to 4.6 | V |
| DC input voltage | $V_{IN}$ | −0.5 to 4.6 | V |
| DC output voltage | $V_{OUT}$ | −0.5 to 4.6 (Note 2) | V |
| | | −0.5 to $V_{CC}$ + 0.5 (Note 3) | |
| Input diode current | $I_{IK}$ | −50 | mA |
| Output diode current | $I_{OK}$ | ±50 (Note 4) | mA |
| DC output current | $I_{OUT}$ | ±50 | mA |
| Power dissipation | $P_D$ | 180 | mW |
| DC $V_{CC}$/ground current | $I_{CC}/I_{GND}$ | ±100 | mA |
| Storage temperature | $T_{stg}$ | −65 to 150 | °C |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. $I_{OUT}$ absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

## Operating Ranges (Note 1)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Power supply voltage | $V_{CC}$ | 1.8 to 3.6 | V |
| | | 1.2 to 3.6 (Note 2) | |
| Input voltage | $V_{IN}$ | −0.3 to 3.6 | V |
| Output voltage | $V_{OUT}$ | 0 to 3.6 (Note 3) | V |
| | | 0 to $V_{CC}$ (Note 4) | |
| Output current | $I_{OH}/I_{OL}$ | ±12 (Note 5) | mA |
| | | ±8 (Note 6) | |
| | | ±4 (Note 7) | |
| Operating temperature | $T_{opr}$ | −40 to 85 | °C |
| Input rise and fall time | dt/dv | 0 to 10 (Note 8) | ns/V |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: OFF state

Note 4: High or low state

Note 5: $V_{CC}$ = 3.0 to 3.6 V

Note 6: $V_{CC}$ = 2.3 to 2.7 V

Note 7: $V_{CC}$ = 1.8 V

Note 8: $V_{IN}$ = 0.8 to 2.0 V, $V_{CC}$ = 3.0 V

## Electrical Characteristics

### DC Characteristics (Ta = –40 to 85°C, 2.7 V < $V_{CC}$ ≦ 3.6 V)

| Characteristics | | Symbol | Test Condition | | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|---|---|
| Input voltage | H-level | $V_{IH}$ | — | | 2.7 to 3.6 | 2.0 | — | V |
| | L-level | $V_{IL}$ | — | | 2.7 to 3.6 | — | 0.8 | |
| Output voltage | H-level | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = –100 μA | 2.7 to 3.6 | $V_{CC}$ – 0.2 | — | V |
| | | | | $I_{OH}$ = –6 mA | 2.7 | 2.2 | — | |
| | | | | $I_{OH}$ = –8 mA | 3.0 | 2.4 | — | |
| | | | | $I_{OH}$ = –12 mA | 3.0 | 2.2 | — | |
| | L-level | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 100 μA | 2.7 to 3.6 | — | 0.2 | |
| | | | | $I_{OL}$ = 6 mA | 2.7 | — | 0.4 | |
| | | | | $I_{OL}$ = 8 mA | 3.0 | — | 0.55 | |
| | | | | $I_{OL}$ = 12 mA | 3.0 | — | 0.8 | |
| Input leakage current | | $I_{IN}$ | $V_{IN}$ = 0 to 3.6 V | | 2.7 to 3.6 | — | ±5.0 | μA |
| 3-state output OFF state current | | $I_{OZ}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$<br>$V_{OUT}$ = 0 to 3.6 V | | 2.7 to 3.6 | — | ±10.0 | μA |
| Power-off leakage current | | $I_{OFF}$ | $V_{IN}$, $V_{OUT}$ = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 2.7 to 3.6 | — | 20.0 | μA |
| | | | $V_{CC}$ ≦ ($V_{IN}$, $V_{OUT}$) ≦ 3.6 V | | 2.7 to 3.6 | — | ±20.0 | |
| Increase in $I_{CC}$ per input | | $\Delta I_{CC}$ | $V_{IH}$ = $V_{CC}$ – 0.6 V | | 2.7 to 3.6 | — | 750 | |

### DC Characteristics (Ta = –40 to 85°C, 2.3 V ≦ $V_{CC}$ ≦ 2.7 V)

| Characteristics | | Symbol | Test Condition | | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|---|---|
| Input voltage | H-level | $V_{IH}$ | — | | 2.3 to 2.7 | 1.6 | — | V |
| | L-level | $V_{IL}$ | — | | 2.3 to 2.7 | — | 0.7 | |
| Output voltage | H-level | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = –100 μA | 2.3 to 2.7 | $V_{CC}$ – 0.2 | — | V |
| | | | | $I_{OH}$ = –4 mA | 2.3 | 2.0 | — | |
| | | | | $I_{OH}$ = –6 mA | 2.3 | 1.8 | — | |
| | | | | $I_{OH}$ = –8 mA | 2.3 | 1.7 | — | |
| | L-level | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 100 μA | 2.3 to 2.7 | — | 0.2 | |
| | | | | $I_{OL}$ = 6 mA | 2.3 | — | 0.4 | |
| | | | | $I_{OL}$ = 8 mA | 2.3 | — | 0.6 | |
| Input leakage current | | $I_{IN}$ | $V_{IN}$ = 0 to 3.6 V | | 2.3 to 2.7 | — | ±5.0 | μA |
| 3-state output OFF state current | | $I_{OZ}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$<br>$V_{OUT}$ = 0 to 3.6 V | | 2.3 to 2.7 | — | ±10.0 | μA |
| Power-off leakage current | | $I_{OFF}$ | $V_{IN}$, $V_{OUT}$ = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 2.3 to 2.7 | — | 20.0 | μA |
| | | | $V_{CC}$ ≦ ($V_{IN}$, $V_{OUT}$) ≦ 3.6 V | | 2.3 to 2.7 | — | ±20.0 | |

## DC Characteristics (Ta = –40 to 85°C, 1.8 V ≦ $V_{CC}$ < 2.3 V)

| Characteristics | | Symbol | Test Condition | | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|---|---|
| Input voltage | H-level | $V_{IH}$ | — | | 1.8 to 2.3 | 0.7 × $V_{CC}$ | — | V |
| | L-level | $V_{IL}$ | — | | 1.8 to 2.3 | — | 0.2 × $V_{CC}$ | |
| Output voltage | H-level | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = –100 μA | 1.8 | $V_{CC}$ – 0.2 | — | V |
| | | | | $I_{OH}$ = –4 mA | 1.8 | 1.4 | — | |
| | L-level | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 100 μA | 1.8 | — | 0.2 | |
| | | | | $I_{OL}$ = 4 mA | 1.8 | — | 0.3 | |
| Input leakage current | | $I_{IN}$ | $V_{IN}$ = 0 to 3.6 V | | 1.8 | — | ±5.0 | μA |
| 3-state output OFF state current | | $I_{OZ}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$<br>$V_{OUT}$ = 0 to 3.6 V | | 1.8 | — | ±10.0 | μA |
| Power-off leakage current | | $I_{OFF}$ | $V_{IN}$, $V_{OUT}$ = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 1.8 | — | 20.0 | μA |
| | | | $V_{CC}$ ≦ ($V_{IN}$, $V_{OUT}$) ≦ 3.6 V | | 1.8 | — | ±20.0 | |

## AC Characteristics (Ta = –40 to 85°C, input: $t_r$ = $t_f$ = 2.0 ns, $C_L$ = 30 pF, $R_L$ = 500 Ω) (Note 1)

| Characteristics | Symbol | Test Condition | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|
| Propagation delay time | $t_{pLH}$<br>$t_{pHL}$ | Figure 1, Figure 2 | 1.8 | 1.5 | 9.8 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 5.6 | |
| | | | 3.3 ± 0.3 | 0.6 | 4.4 | |
| 3-state output enable time | $t_{pZL}$<br>$t_{pZH}$ | Figure 1, Figure 3 | 1.8 | 1.5 | 9.8 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 6.5 | |
| | | | 3.3 ± 0.3 | 0.6 | 5.0 | |
| 3-state output disable time | $t_{pLZ}$<br>$t_{pHZ}$ | Figure 1, Figure 3 | 1.8 | 1.5 | 7.0 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 3.9 | |
| | | | 3.3 ± 0.3 | 0.6 | 3.6 | |
| Output to output skew | $t_{osLH}$<br>$t_{osHL}$ | (Note 2) | 1.8 | — | 0.5 | ns |
| | | | 2.5 ± 0.2 | — | 0.5 | |
| | | | 3.3 ± 0.3 | — | 0.5 | |

Note 1: For $C_L$ = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.
($t_{osLH}$ = $|t_{pLHm} - t_{pLHn}|$, $t_{osHL}$ = $|t_{pHLm} - t_{pHLn}|$)

## Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

| Characteristics | Symbol | Test Condition | $V_{CC}$ (V) | Typ. | Unit |
|---|---|---|---|---|---|
| Quiet output maximum dynamic $V_{OL}$ | $V_{OLP}$ | $V_{IH}$ = 1.8 V, $V_{IL}$ = 0 V (Note) | 1.8 | 0.15 | V |
| | | $V_{IH}$ = 2.5 V, $V_{IL}$ = 0 V (Note) | 2.5 | 0.25 | |
| | | $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V (Note) | 3.3 | 0.35 | |
| Quiet output minimum dynamic $V_{OL}$ | $V_{OLV}$ | $V_{IH}$ = 1.8 V, $V_{IL}$ = 0 V (Note) | 1.8 | −0.15 | V |
| | | $V_{IH}$ = 2.5 V, $V_{IL}$ = 0 V (Note) | 2.5 | −0.25 | |
| | | $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V (Note) | 3.3 | −0.35 | |
| Quiet output minimum dynamic $V_{OH}$ | $V_{OHV}$ | $V_{IH}$ = 1.8 V, $V_{IL}$ = 0 V (Note) | 1.8 | 1.55 | V |
| | | $V_{IH}$ = 2.5 V, $V_{IL}$ = 0 V (Note) | 2.5 | 2.05 | |
| | | $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V (Note) | 3.3 | 2.65 | |

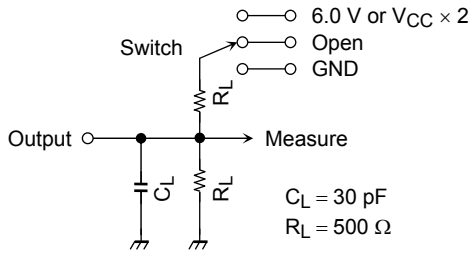
Note: Parameter guaranteed by design.

## Capacitive Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | $V_{CC}$ (V) | Typ. | Unit |
|---|---|---|---|---|---|
| Input capacitance | $C_{IN}$ | — | 1.8, 2.5, 3.3 | 6 | pF |
| Output capacitance | $C_O$ | — | 1.8, 2.5, 3.3 | 7 | pF |
| Power dissipation capacitance | $C_{PD}$ | $f_{IN}$ = 10 MHz (Note) | 1.8, 2.5, 3.3 | 20 | pF |

Note: $C_{PD}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

## AC Test Circuit




| Parameter | Switch | |
|---|---|---|
| $t_{pLH}$, $t_{pHL}$ | Open | |
| $t_{pLZ}$, $t_{pZL}$ | 6.0 V | @$V_{CC}$ = 3.3 ± 0.3 V |
| | $V_{CC}$ × 2 | @$V_{CC}$ = 2.5 ± 0.2 V |
| | | @$V_{CC}$ = 1.8 V |
| $t_{pHZ}$, $t_{pZH}$ | GND | |

**Figure 1**

**AC Waveform**

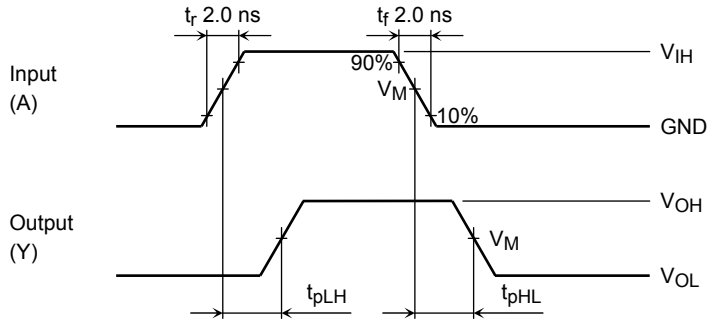



**Figure 2 $t_{pLH}$, $t_{pHL}$**

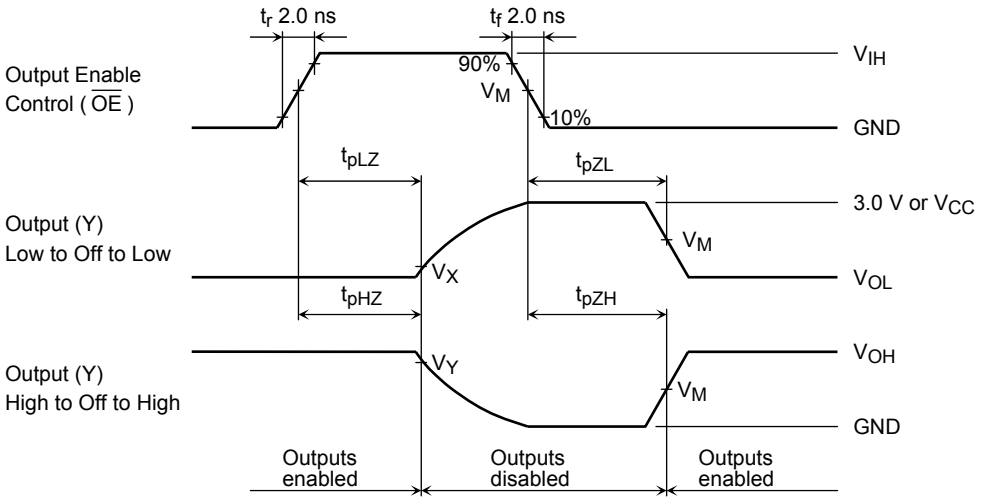
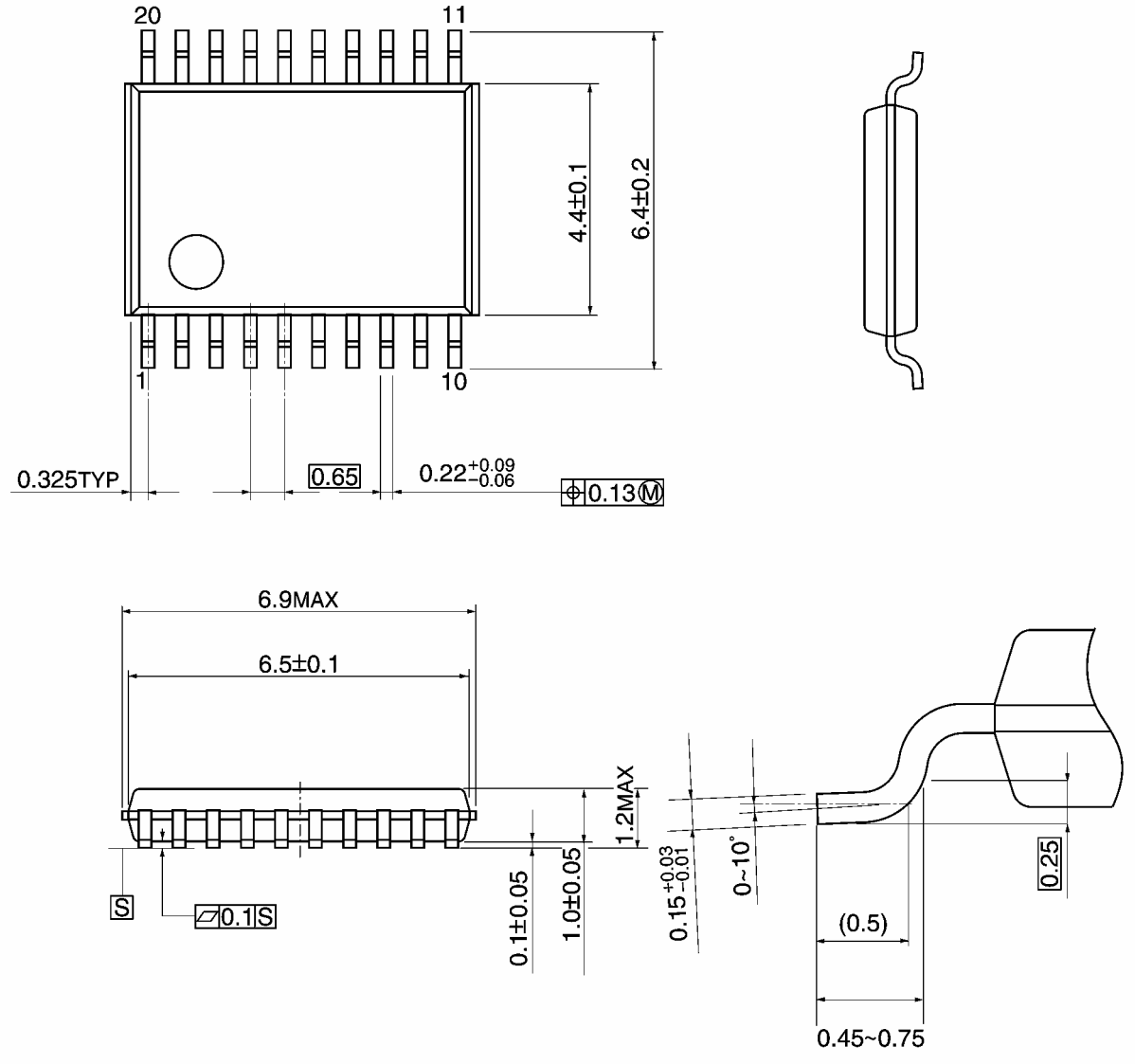



**Figure 3 $t_{pLZ}$, $t_{pHZ}$, $t_{pZL}$, $t_{pZH}$**

| Symbol | $V_{CC}$ | | |
|---|---|---|---|
| | 3.3 ± 0.3 V | 2.5 ± 0.2 V | 1.8 V |
| $V_{IH}$ | 2.7 V | $V_{CC}$ | $V_{CC}$ |
| $V_M$ | 1.5 V | $V_{CC}/2$ | $V_{CC}/2$ |
| $V_X$ | $V_{OL}$ + 0.3 V | $V_{OL}$ + 0.15 V | $V_{OL}$ + 0.15 V |
| $V_Y$ | $V_{OH}$ − 0.3 V | $V_{OH}$ − 0.15 V | $V_{OH}$ − 0.15 V |

## Package Dimensions

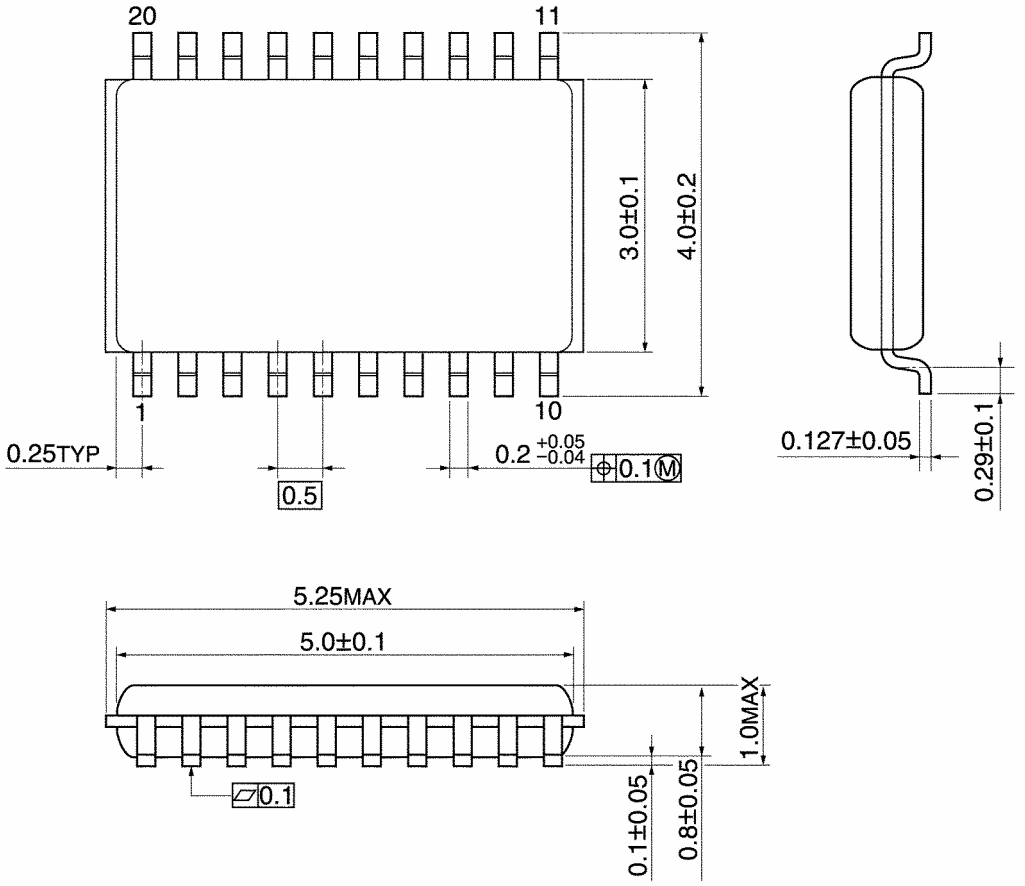
TSSOP20-P-0044-0.65A Unit: mm




Weight: 0.08 g (typ.)

## Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm




Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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